

Memory capacity	Memory Configuration	Function mode	Access/Clock (ns)	Type No.	Package Outline
2M	64Kx32	V _{CC} = 3.13 to 3.47V Sync. Burst Pipeline	5.0/7.5	M5M5V2132GP-5H ★★	100P6A-A
			5.0/8.5	M5M5V2132GP-5 ★★	
			5.5/10.0	M5M5V2132GP-6 ★★	
		V _{CC} = 3.13 to 3.6V Sync. Burst Pipeline	7.0/13.3	M5M5V2132GP-7 ★★	
			8.0/15.0	M5M5V2132GP-8 ★★	
4M	4Mx1	V _{CC} = 3.13 to 3.6V	12	M5M5V4R01J-12 ★★	32P0K
			15	M5M5V4R01J-15 ★★	32P0K
			20	M5M5V4R01J-20 ★★	32P0K
	1Mx4	V _{CC} = 3.13 to 3.6V	12	M5M5V4R04J-12 ★★	32P0K
			15	M5M5V4R04J-15 ★★	32P0K
			20	M5M5V4R04J-20 ★★	32P0K
	512Kx8	V _{CC} = 3.13 to 3.6V	12	M5M5V4R08J-12 ★★	36P0K
			15	M5M5V4R08J-15 ★★	36P0K
			20	M5M5V4R08J-20 ★★	36P0K

■ STATIC RAM MODULES

Memory capacity	Memory Configuration	Load memories	Max. access time (ns)	Max. power dissipation (mW)	Type No.	Outward dimensions (W×H×D)
2M	256Kx8	M5M51008BVP/BRVx1	85	511.5	MH2568BBNA-85L,-85H	43.0×19.14×5.1 32pin DIP
			100		MH2568BBNA-10L,-10H	
			120		MH2568BBNA-12L,-12H	
4M	512Kx8	M5M51008BVPx2 + M5M51008BRVx2	85	561	MH5128BANA-85L,-85H	46.4×19.14×5.8 32pin DIP
			100		MH5128BANA-10L,-10H	
			120		MH5128BANA-12L,-12H	
		M5M51008BFPx4	85	561	MH5128BUNA-85L,-85H	56.5×21.0×8.6 32pin DIP
			100		MH5128BUNA-10L,-10H	
			120		MH5128BUNA-12L,-12H	
8M	1Mx8	M5M51008BVPx4 + M5M51008BRVx4	85	627	MH1M08BTNA-85L,-85H	53.4×23.0×6.4 36pin DIP
			100		MH1M08BTNA-10L,-10H	
			120		MH1M08BTNA-12L,-12H	
16M	2Mx8	M5M51008BVPx8 + M5M51008BRVx8	85	759	MH2M08BTNA-85L,-85H	53.4×23.0×11.0 36pin DIP
			100		MH2M08BTNA-10L,-10H	
			120		MH2M08BTNA-12L,-12H	

● Burst Static RAM modules

Memory capacity	Memory Configuration	Load memories	Access/Clock (ns)	Type No.	Outward dimensions (W×H×D)
2M	32Kx64	M5M5V1132FPx2 + M5M5278DJx1	8.0/15.0	MH32S64R3N-8	110.236×28.702×5.955
		M5M5V1132GPx2 + M5M5278DJx1		MH32S64TR3N-8	110.236×28.702×5.955
4M	64Kx64	M5M5V1132FPx4 + M5M5278DJx1	8.0/15.0	MH64S64R3N-8	110.236×28.7×8.655
		M5M5V1132GPx4 + M5M5278DJx1		MH64S64TR3N-8	110.236×28.7×7.095